

TOSHIBA Field-Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

# SSM3K7002BF

High-Speed Switching Applications

Analog Switch Applications

Unit: mm

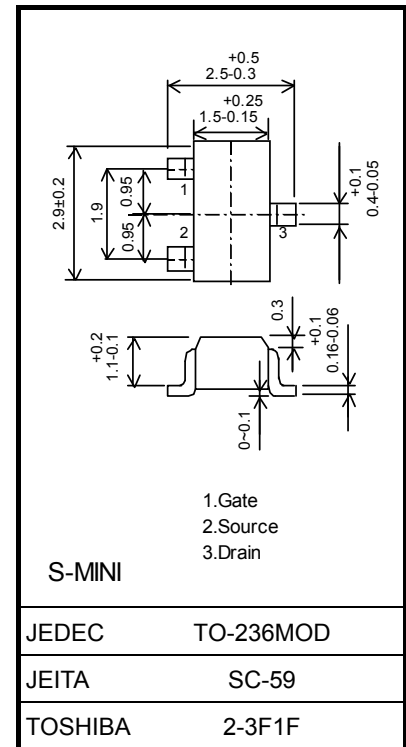
- Small package
- Low ON-resistance :  $R_{DS(ON)} = 3.3 \Omega$  (max) (@ $V_{GS} = 4.5 V$ )  
 :  $R_{DS(ON)} = 2.6 \Omega$  (max) (@ $V_{GS} = 5 V$ )  
 :  $R_{DS(ON)} = 2.1 \Omega$  (max) (@ $V_{GS} = 10 V$ )

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics           |       | Symbol    | Rating     | Unit |
|---------------------------|-------|-----------|------------|------|
| Drain-source voltage      |       | $V_{DSS}$ | 60         | V    |
| Gate-source voltage       |       | $V_{GSS}$ | ±20        | V    |
| Drain current             | DC    | $I_D$     | 200        | mA   |
|                           | Pulse | $I_{DP}$  | 800        |      |
| Drain power dissipation   |       | $P_D$     | 200        | mW   |
| Channel temperature       |       | $T_{ch}$  | 150        | °C   |
| Storage temperature range |       | $T_{stg}$ | -55 to 150 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 12 mg (typ.)

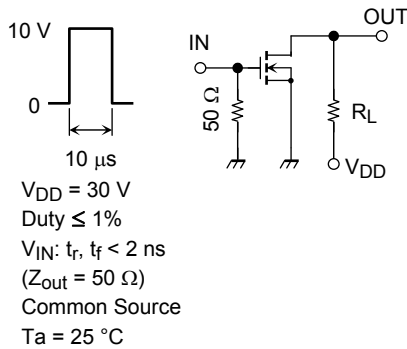
## Electrical Characteristics (Ta = 25°C)

| Characteristics                |                     | Symbol                                  | Test Condition   | Min  | Typ   | Max  | Unit |
|--------------------------------|---------------------|---|--|------|-------|------|------|
| Gate leakage current           |                     | $I_{GSS}$                               | $V_{GS} = \pm 20 V, V_{DS} = 0 V$                          | —    | —     | ±10  | μA   |
| Drain-source breakdown voltage | $V_{(BR)DSS}$       | $I_D = 10 mA, V_{GS} = 0 V$             | 60   | —    | —     | V    |      |
|                                | $V_{(BR)DSX}$       | $I_D = 10 mA, V_{GS} = -10 V$           | 45   | —    | —     |      |      |
| Drain cutoff current           |                     | $I_{DSS}$                               | $V_{DS} = 60 V, V_{GS} = 0 V$                              | —    | —     | 1    | μA   |
| Gate threshold voltage         |                     | $V_{th}$                                | $V_{DS} = 10 V, I_D = 0.25 mA$                             | 1.5  | —     | 3.1  | V    |
| Forward transfer admittance    |                     | $ Y_{fs} $                              | $V_{DS} = 10 V, I_D = 200 mA$ (Note 1)                     | 225  | —     | —    | mS   |
| Drain-source ON-resistance     | $R_{DS(ON)}$        | $I_D = 500 mA, V_{GS} = 10 V$ (Note 1)  | —  | 1.62 | 2.1   | Ω    |      |
|                                |                     | $I_D = 100 mA, V_{GS} = 5 V$ (Note 1)   | —  | 1.90 | 2.6   |      |      |
|                                |                     | $I_D = 100 mA, V_{GS} = 4.5 V$ (Note 1) | —  | 2.10 | 3.3   |      |      |
| Input capacitance              |                     | $C_{iss}$                               | $V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz$                   | —    | 17.0  | —    | pF   |
| Reverse transfer capacitance   |                     | $C_{riss}$                              |  | —    | 1.9   | —    |      |
| Output capacitance             |                     | $C_{oss}$                               |  | —    | 3.6   | —    |      |
| Switching time                 | Turn-on delay time  | $t_{d(on)}$                             | $V_{DD} = 30 V, I_D = 200 mA, V_{GS} = 0 \text{ to } 10 V$ | —    | 3.3   | 6.6  | ns   |
|                                | Turn-off delay time | $t_{d(off)}$                            |  | —    | 14.5  | 40   |      |
| Drain-source forward voltage   |                     | $V_{DSF}$                               | $I_D = -200 mA, V_{GS} = 0 V$ (Note 1)                     | —    | -0.84 | -1.2 | V    |

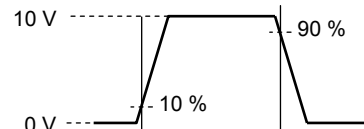
Note1: Pulse test

## Switching Time Test Circuit

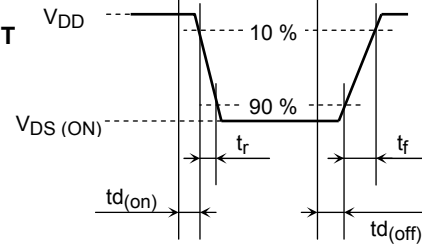
### (a) Test circuit



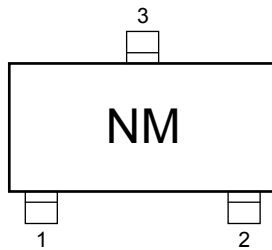
### (b) $V_{IN}$



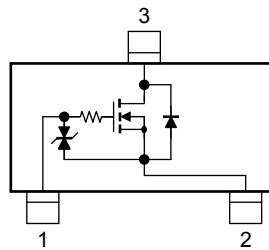
### (c) $V_{OUT}$



## Marking



## Equivalent Circuit (top view)

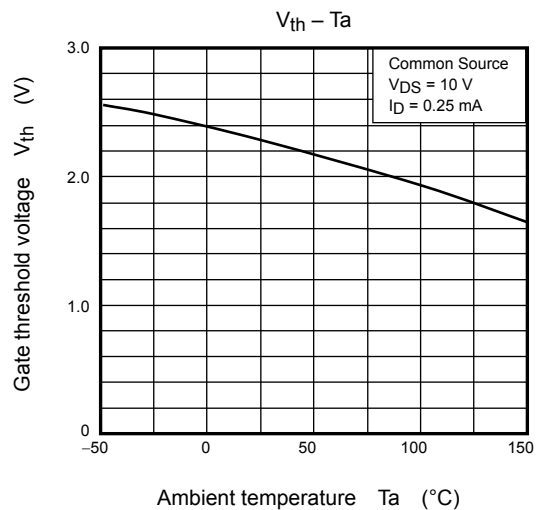
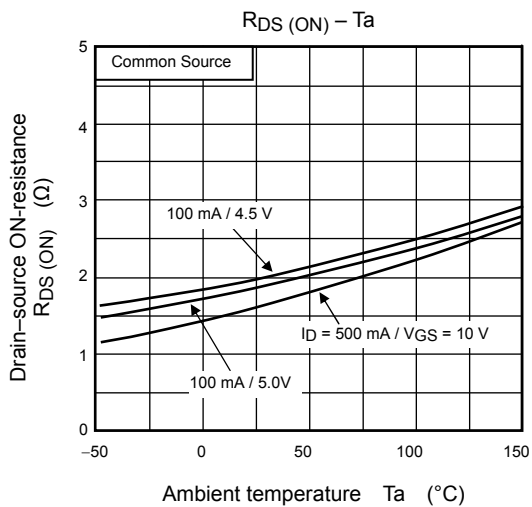
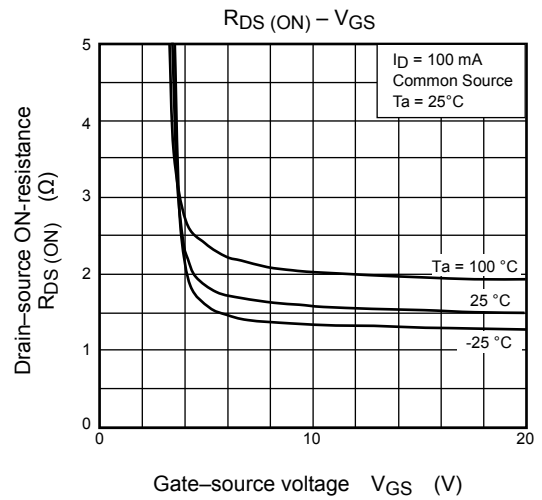
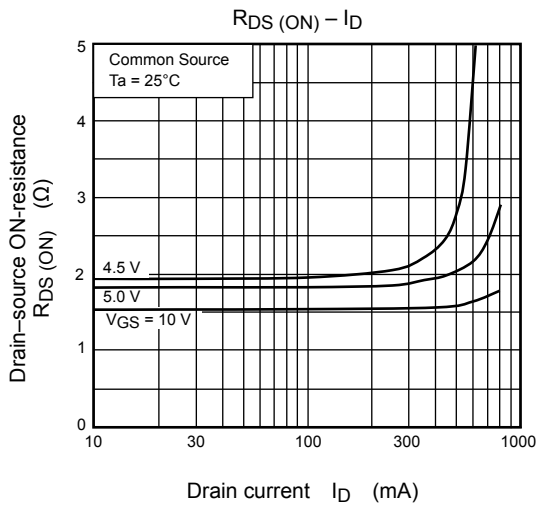
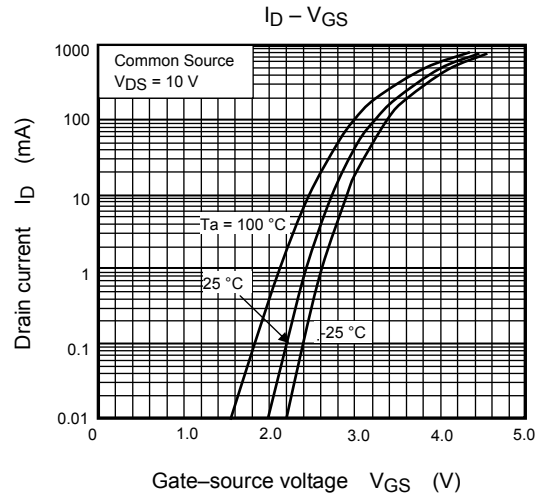
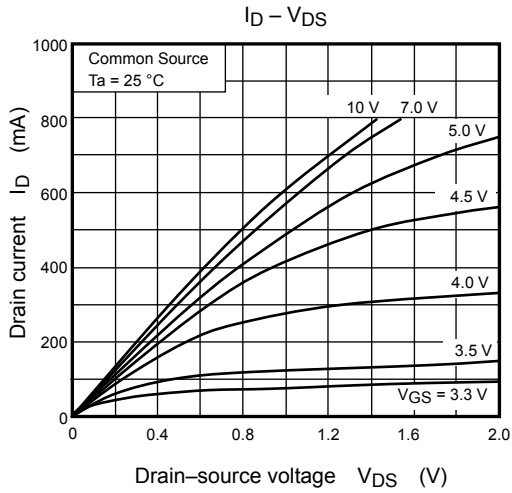


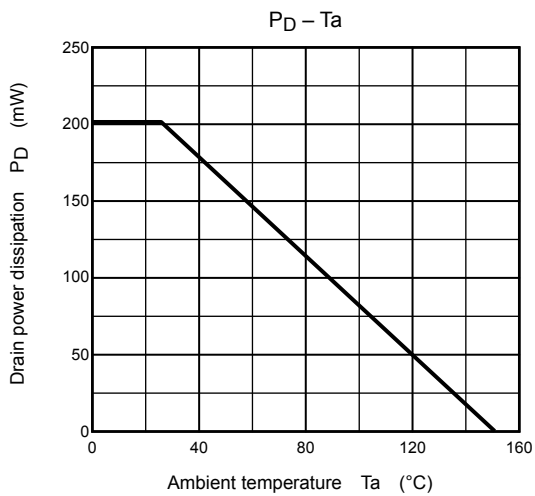
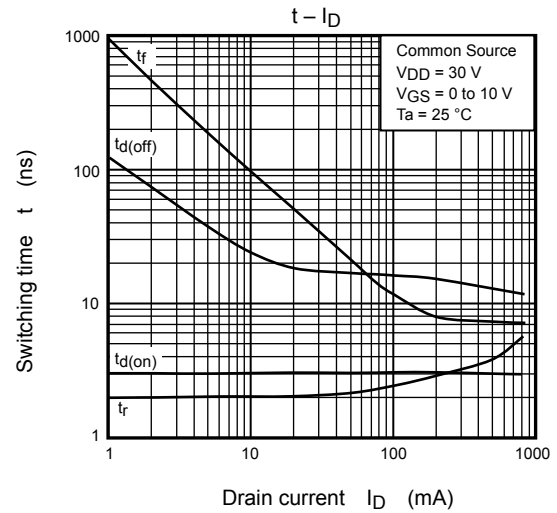
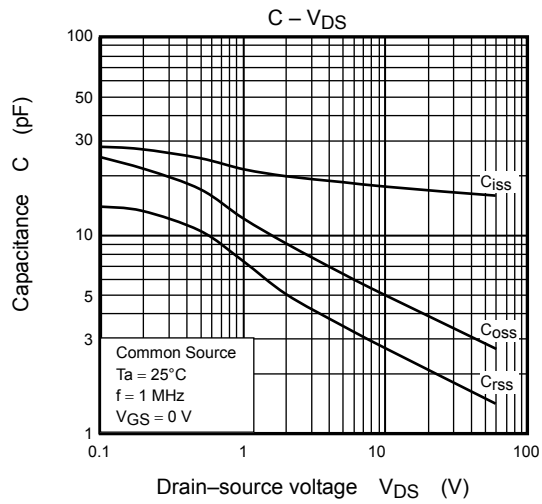
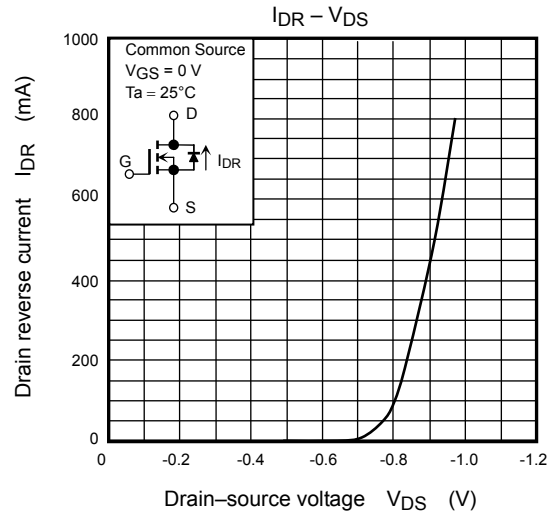
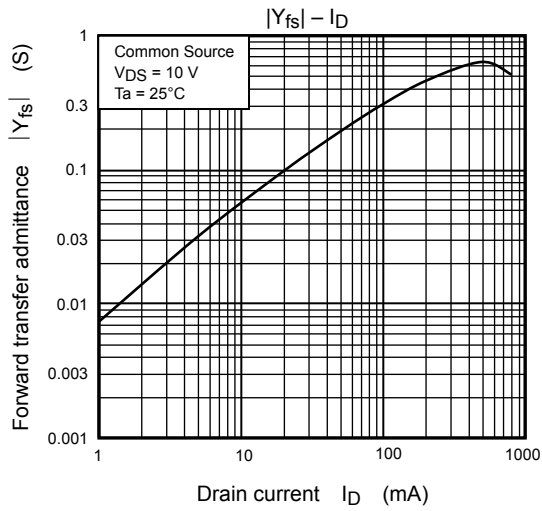
## Precaution

Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to be low (0.25 mA for the SSM3K7002BF). Then, for normal switching operation,  $V_{GS(on)}$  must be higher than  $V_{th}$ , and  $V_{GS(off)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ . Take this into consideration when using the device.

## Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.





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